

**IR-Lumineszenzdiode (850 nm) mit hoher Ausgangsleistung**  
**High Power Infrared Emitter (850 nm)**  
**Lead (Pb) Free Product - RoHS Compliant**  
**SFH 4050**

**Für Neuentwicklungen / for new designs**



**Vorläufige Daten / Preliminary Data**

**Wesentliche Merkmale**

- Sehr kleines Gehäuse:  
(LxBxH) 1.7 mm x 0.8 mm x 0.65 mm
- Emissionswellenlänge typ. 850 nm
- Gegurtet lieferbar
- Sehr hohe Gesamtleistung

**Anwendungen**

- Miniaturlichtschranken
- Industrieelektronik
- „Messen/Steuern/Regeln“
- Sensorik
- Alarm- und Sicherungssysteme
- IR-Freiraumübertragung

**Sicherheitshinweise**

Je nach Betriebsart emittieren diese Bauteile hochkonzentrierte, nicht sichtbare Infrarot-Strahlung, die gefährlich für das menschliche Auge sein kann. Produkte, die diese Bauteile enthalten, müssen gemäß den Sicherheitsrichtlinien der IEC-Normen 60825-1 und 62471 behandelt werden.

**Features**

- Very small package:  
(LxWxH) 1.7 mm x 0.8 mm x 0.65 mm
- Peak wavelength typ. 850 nm
- Available on tape and reel
- High optical total power

**Applications**

- Miniature photointerrupters
- Industrial electronics
- For drive and control circuits
- Sensor technology
- Alarm and safety equipment
- IR free air transmission

**Safety Advises**

Depending on the mode of operation, these devices emit highly concentrated non visible infrared light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1 and IEC 62471.

Typ Type	Bestellnummer Ordering Code	Strahlstärkegruppierung <sup>1)</sup> ( $I_F = 100 \text{ mA}$ , $t_p = 20 \text{ ms}$ ) Radiant Intensity Grouping <sup>1)</sup> $I_e \text{ (mW/sr)}$
SFH 4050	Q65110A6460	$\geq 4$ (typ. 7)

<sup>1)</sup> gemessen bei einem Raumwinkel  $\Omega = 0.01 \text{ sr}$  / measured at a solid angle of  $\Omega = 0.01 \text{ sr}$



**ATTENTION - Observe Precautions For Handling - Electrostatic Sensitive Device**

**Grenzwerte** ( $T_A = 25\text{ °C}$ )**Maximum Ratings**

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Betriebs- und Lagertemperatur Operating and storage temperature range	$T_{op}, T_{stg}$	- 40 ... + 100	°C
Sperrspannung Reverse voltage	$V_R$	5	V
Vorwärtsgleichstrom Forward current	$I_F$	100	mA
Stoßstrom, $t_p = 200\ \mu\text{s}$ , $D = 0$ Surge current	$I_{FSM}$	1	A
Verlustleistung Power dissipation	$P_{tot}$	180	mW
Wärmewiderstand Sperrschicht - Umgebung bei Montage auf FR4 Platine, Padgröße je $5\ \text{mm}^2$ Thermal resistance junction - ambient mounted on PC-board (FR4), pads size $5\ \text{mm}^2$ each	$R_{thJA}$	450	K/W
Wärmewiderstand Sperrschicht - Lötstelle bei Montage auf Metall-Block Thermal resistance junction - soldering point, mounted on metal block	$R_{thJS}$	250	K/W

**Kennwerte** ( $T_A = 25\text{ °C}$ )**Characteristics**

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Wellenlänge der Strahlung Wavelength at peak emission $I_F = 100\ \text{mA}$	$\lambda_{peak}$	850	nm
Spektrale Bandbreite bei 50% von $I_{max}$ Spectral bandwidth at 50% of $I_{max}$ $I_F = 100\ \text{mA}$	$\Delta\lambda$	35	nm
Abstrahlwinkel Half angle	$\varphi$	$\pm 80$	Grad deg.
Aktive Chipfläche Active chip area	$A$	0.09	$\text{mm}^2$
Abmessungen der aktiven Chipfläche Dimension of the active chip area	$L \times B$ $L \times W$	$0.3 \times 0.3$	$\text{mm}^2$

Kennwerte ( $T_A = 25\text{ °C}$ )

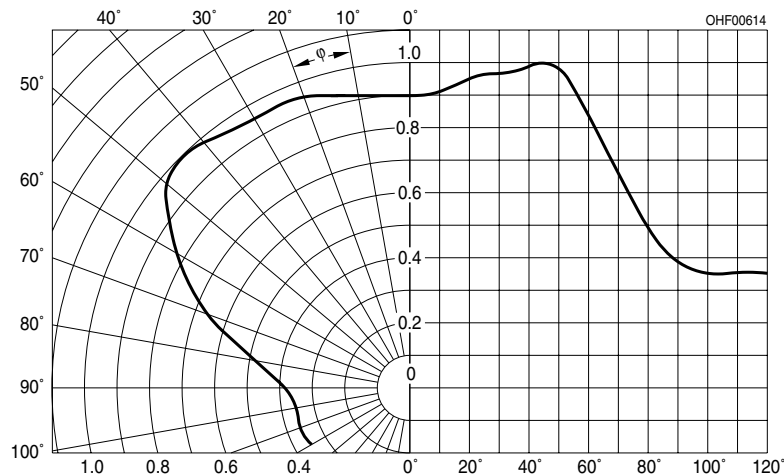
Characteristics (cont'd)

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Schaltzeiten, $I_e$ von 10% auf 90% und von 90% auf 10%, bei $I_F = 100\text{ mA}$ , $R_L = 50\ \Omega$ Switching times, $I_e$ from 10% to 90% and from 90% to 10%, $I_F = 100\text{ mA}$ , $R_L = 50\ \Omega$	$t_r, t_f$	12	ns
Kapazität, Capacitance $V_R = 0\text{ V}$ , $f = 1\text{ MHz}$	$C_o$	15	pF
Durchlassspannung Forward voltage $I_F = 100\text{ mA}$ , $t_p = 20\text{ ms}$ $I_F = 1\text{ A}$ , $t_p = 100\ \mu\text{s}$	$V_F$ $V_F$	1.5 (< 1.8) 2.4 (< 3.0)	V V
Sperrstrom Reverse current $V_R = 5\text{ V}$	$I_R$	not designed for reverse operation	$\mu\text{A}$
Gesamtstrahlungsfluss Total radiant flux $I_F = 100\text{ mA}$ , $t_p = 20\text{ ms}$	$\Phi_{e\text{ typ}}$	50	mW
Temperaturkoeffizient von $I_e$ bzw. $\Phi_e$ , $I_F = 100\text{ mA}$ Temperature coefficient of $I_e$ or $\Phi_e$ , $I_F = 100\text{ mA}$	$TC_I$	- 0.5	%/K
Temperaturkoeffizient von $V_F$ , $I_F = 100\text{ mA}$ Temperature coefficient of $V_F$ , $I_F = 100\text{ mA}$	$TC_V$	- 0.7	mV/K
Temperaturkoeffizient von $\lambda$ , $I_F = 100\text{ mA}$ Temperature coefficient of $\lambda$ , $I_F = 100\text{ mA}$	$TC_\lambda$	+ 0.2	nm/K

**Strahlstärke  $I_e$  in Achsrichtung<sup>1)</sup>**gemessen bei einem Raumwinkel  $\Omega = 0.01$  sr**Radiant Intensity  $I_e$  in Axial Direction**at a solid angle of  $\Omega = 0.01$  sr

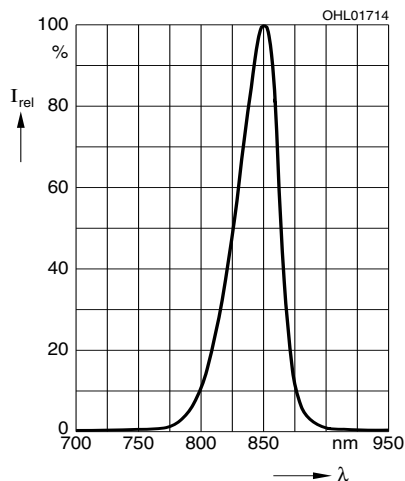
Bezeichnung Parameter	Symbol	Werte Values		Einheit Unit
		SFH 4050-P	SFH 4050-Q	
Strahlstärke Radiant intensity $I_F = 100$ mA, $t_p = 20$ ms	$I_{e \text{ min}}$ $I_{e \text{ max}}$	4 8	6.3 12.5	mW/sr mW/sr
Strahlstärke Radiant intensity $I_F = 1$ A, $t_p = 100$ $\mu$ s	$I_{e \text{ typ}}$	50	70	mW/sr

<sup>1)</sup> Nur eine Gruppe in einer Verpackungseinheit (Streuung kleiner 2:1) /  
Only one group in one packing unit (variation lower 2:1)

**Abstrahlcharakteristik****Radiation Characteristics  $I_{\text{rel}} = f(\varphi)$** 

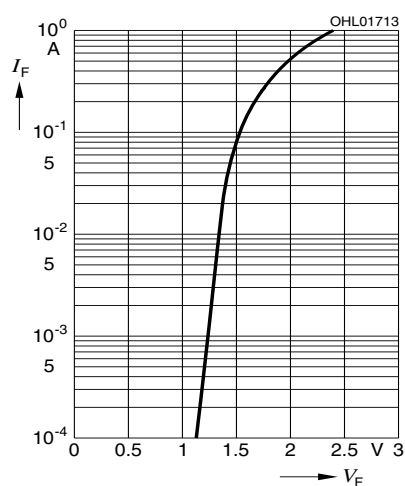
**Relative Spectral Emission**

$I_{rel} = f(\lambda)$



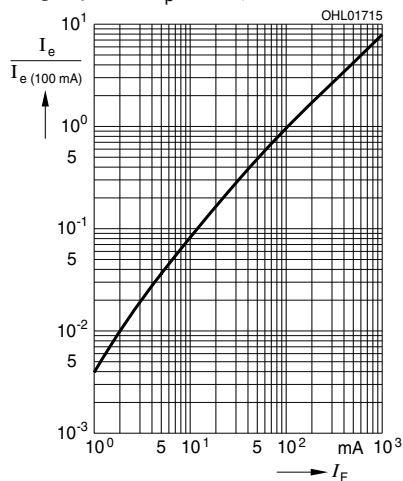
**Forward Current  $I_F = f(V_F)$**

Single pulse,  $t_p = 20 \mu s$



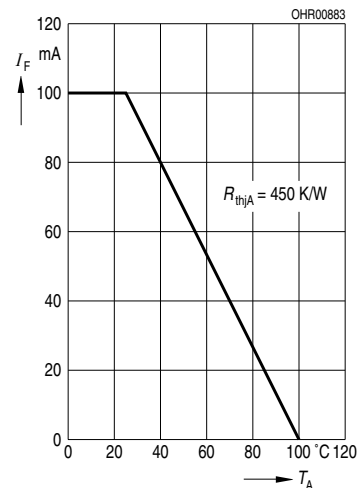
**Radiant Intensity  $\frac{I_e}{I_e 100 \text{ mA}} = f(I_F)$**

Single pulse,  $t_p = 20 \mu s$



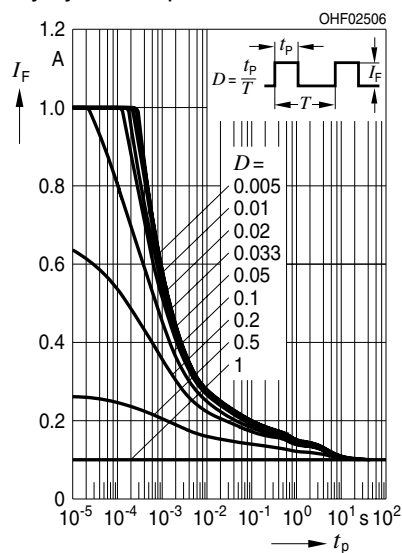
**Max. Permissible Forward Current**

$I_F = f(T_A), R_{thJA} = 450 \text{ K/W}$

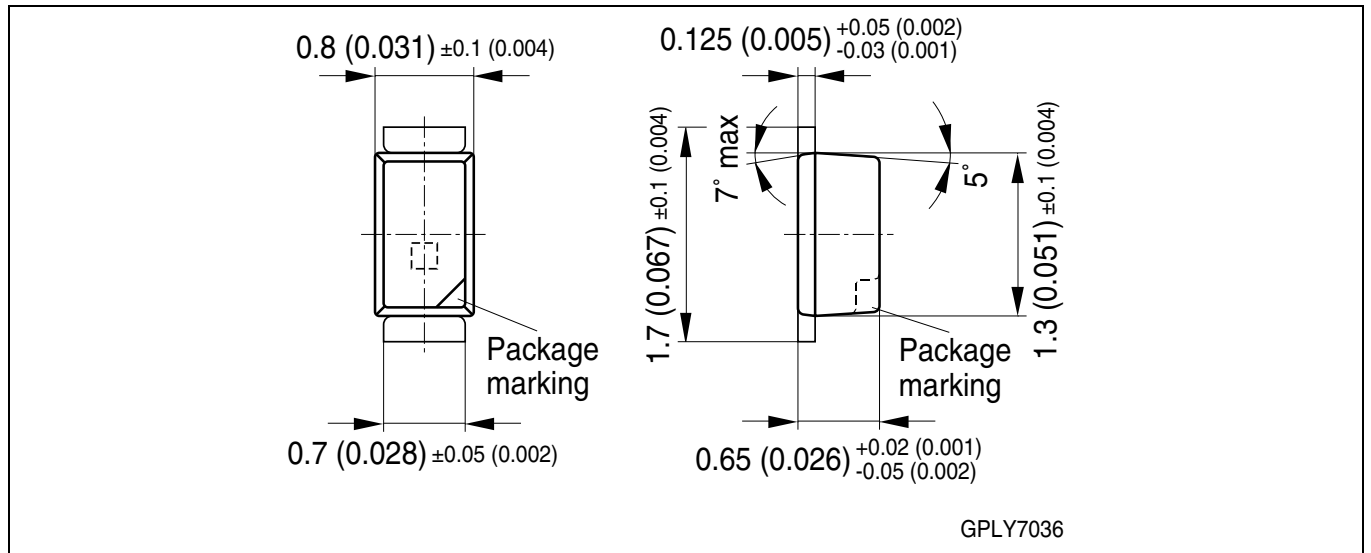


**Permissible Pulse Handling Capability  $I_F = f(\tau), T_A = 25^\circ C$**

duty cycle  $D = \text{parameter}$



**Maßzeichnung  
Package Outlines**

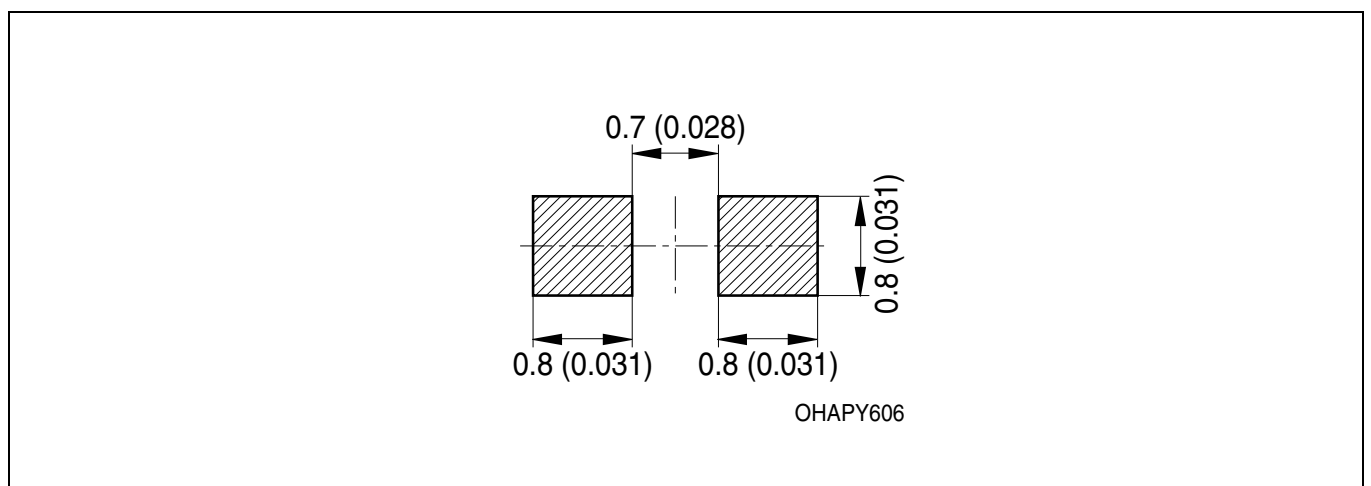


Maße in mm (inch) / Dimensions in mm (inch).

Gehäuse / Package	Epoxydharz, diffus / Epoxy, diffuse
Farbe / Colour	Farblos / colourless
Gehäusemarkierung/ Package marking	Anode

**Empfohlenes Lötpad Design  
Recommended Solder Pad Design**

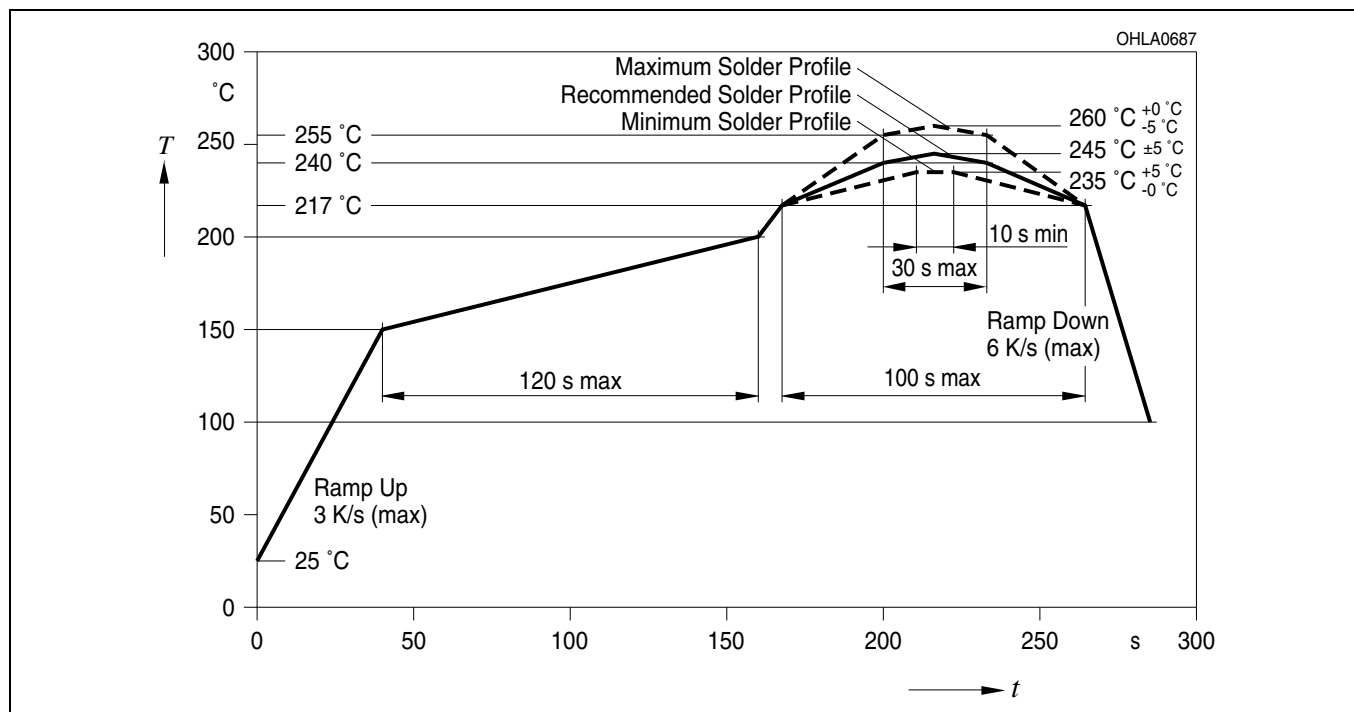
Reflow Löten  
Reflow Soldering



Maße in mm (inch) / Dimensions in mm (inch).

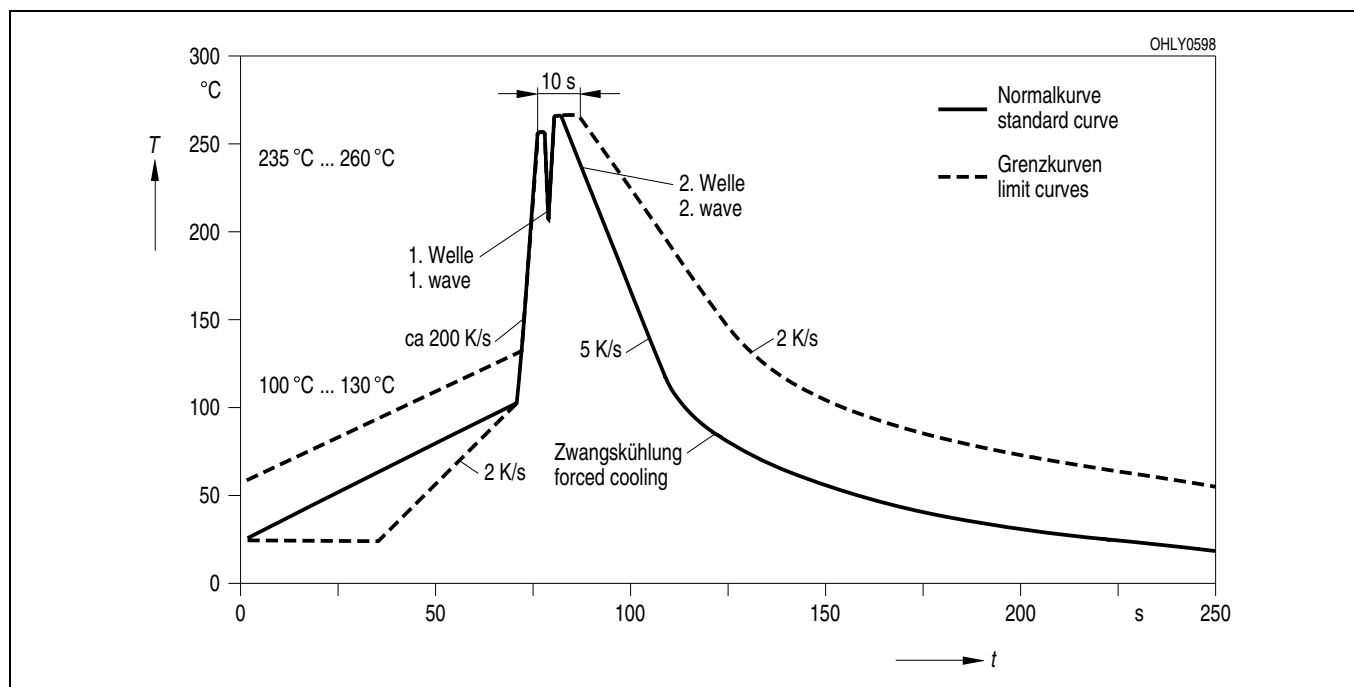
**Lötbedingungen**  
**Soldering Conditions**  
**Reflow Lötprofil für bleifreies Löt**  
**Reflow Soldering Profile for lead free soldering**

Vorbehandlung nach JEDEC Level 2  
 Preconditioning acc. to JEDEC Level 2  
 (nach J-STD-020C)  
 (acc. to J-STD-020C)



**Wellenlöt (TTW)**  
**TTW Soldering**

(nach CECC 00802)  
 (acc. to CECC 00802)



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